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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/631,362	07/31/2003	Scung Woo Shin	29936/39461	2146
4743 75	590 11/18/2003		EXAM	NER
MARSHALL, GERSTEIN & BORUN LLP 6300 SEARS TOWER			GHYKA, ALEXANDER G	
233 S. WACKER DRIVE CHICAGO, IL 60606			ART UNIT	PAPER NUMBER
			2812	

DATE MAILED: 11/18/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

		W.			
	Application No.	Applicant(s)			
Office Action Summan	10/631,362	SHIN ET AL.			
Office Action Summary	Examin r	Art Unit			
	Alexander G. Ghyka	2812			
Th MAILING DATE of this communication a Period for Reply	ppears on the cover she it with	the correspondence address			
A SHORTENED STATUTORY PERIOD FOR REP THE MAILING DATE OF THIS COMMUNICATION  - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a re If NO period for reply is specified above, the maximum statutory perio - Failure to reply within the set or extended period for reply will, by statt - Any reply received by the Office later than three months after the mail earned patent term adjustment. See 37 CFR 1.704(b).  Status	I. 1.136(a). In no event, however, may a repi eply within the statutory minimum of thirty (i d will apply and will expire SIX (6) MONTH ute, cause the application to become ABAN	ly be timely filed 30) days will be considered timely. IS from the mailing date of this communication. IDONED (35 U.S.C. § 133).			
1) Responsive to communication(s) filed on	·				
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ Thi	is action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims					
4) Claim(s) 1-6 is/are pending in the application 4a) Of the above claim(s) is/are withdr 5) Claim(s) is/are allowed. 6) Claim(s) 1-6 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and	rawn from consideration.	ALEXANDER GHYKA PRIMARY EXAMINER  AU 28 12  ALL  ALL  ALL  ALL  ALL  ALL  ALL  A			
Application Papers		// ()			
9) The specification is objected to by the Examin					
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).  11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.					
Priority under 35 U.S.C. §§ 119 and 120					
12)⊠ Acknowledgment is made of a claim for foreign	an priority under 35 H.S.C. & 1	119(a)-(d) or (f)			
a) □ All b) □ Some * c) □ None of:  1. □ Certified copies of the priority documer  2. □ Certified copies of the priority documer  3. □ Copies of the certified copies of the pri application from the International Bure  * See the attached detailed Office action for a lis  13) □ Acknowledgment is made of a claim for domes since a specific reference was included in the f 37 CFR 1.78.  a) □ The translation of the foreign language p  14) □ Acknowledgment is made of a claim for domes reference was included in the first sentence of	nts have been received. Ints have been received in Applicationity documents have been reau (PCT Rule 17.2(a)). Inst of the certified copies not restic priority under 35 U.S.C. § Inst sentence of the specification has bee stic priority under 35 U.S.C. §	ceived in this National Stage ceived. 119(e) (to a provisional application) on or in an Application Data Sheet. n received. § 120 and/or 121 since a specific			
Attachment(s)					
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) 🔲 Notice of Info	nmary (PTO-413) Paper No(s) rmal Patent Application (PTO-152)			

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## **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1-6 are rejected under 35 U.S.C. 102(e) as being anticipated by Irino et al (US 6,468,926).

The present claims generally require loading a silicon substrate into an oxidization furnace, implanting oxygen, implanting an inert gas to exhaust the oxygen in the furnace, raising the temperature, stabilizing the temperature, implementing a nitrification process, and stopping implantation of the nitrogen based source gas and rapidly cooling the oxidization furnace while implanting the inert gas into the oxidization furnace.

Irino et al disclose loading a silicon wafer into a furnace, oxidizing the silicon wafer, purging the reaction chamber with an inert gas, raising the temperature, and introducing a nitrogen to form an oxy nitride film. See column 9, lines 45 to column 10, line 5 and Figure 2. Moreover, Irino et al disclose lowering the temperature of the silicon wafer while gas is purged from the reaction chamber by using an inert gas. See column 10, lines 5-15. Irino et al disclose NO or nitrous oxide as the nitrogen containing

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gas as required by present Claim 2. See column 9, lines 60-68. Futhermore, Irino et al disclose the dilution of NO or nitrous oxide with N2, as required by present Claim 3. See column 10, lines 50-55. Irino et al, disclose the temperature ranges as required by present Claims 4 and 5. Furthermore, Irino et al disclose an annealing process before cooling the furnace as required in present Claim 6. See Figure 2 and column 9, lines 15-35. Therefore, Claims 1-6 are anticipated by the Irino et al reference.

## Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Alexander G. Ghyka whose telephone number is (703) 305-3407. The examiner can normally be reached on Wednesday off.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John F Niebling can be reached on (703) 308-3325. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

> ALEXANDER GHYKA PRIMARY EXAMINER

AGG